

VS-GB100NH120N

VS-GB100NH120N Information

Heisener.com	Part Number Manufacturer Category Description Package	VS-GB100NH120N Vishay Semiconductor Diodes Division Discrete Semiconductor Products Transistors - IGBTs - Modules IGBT 1200V 200A 833W INT-A-PAK Double INT-A-PAK (3 + 4) For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



VS-GB100NH120N Specifications

Manufacturer Part Number	VS-GB100NH120N
Manufacturer	Vishay Semiconductor Diodes Division
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Modules
Package	Double INT-A-PAK (3 + 4)
Series	-
IGBT Type	-
Configuration	Single
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	200A
Power - Max	833W
Vce(on) (Max) @ Vge, Ic	2.35V @ 15V, 100A
Current - Collector Cutoff (Max)	5mA
Input Capacitance (Cies) @ Vce	8.58nF @ 25V
Input	Standard
NTC Thermistor	No
Operating Temperature	150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	Double INT-A-PAK (3 + 4)
Supplier Device Package	Double INT-A-PAK
	Report errors?

VS-GB100NH120N Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

VS-GB100NH120N Payment Methods





If you have any question about VS-GB100NH120N, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com